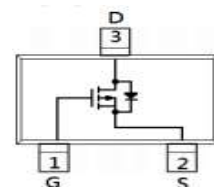


Features

- $V_{DS}=30V, I_D=4.2A$
- $R_{DS(ON)}=52m\Omega$ (TYP.) $V_{GS}=10V$
- Reliable and Rugged
- Avalanche Rated
- Low On-Resistance

SOT23-3L



Applications

- Load Switch
- Power management in portable/desktop PCs
- DC/DC conversiong

Ordering Information

Device	package	Device Marking	Package Qty.
AO3434	SOT23-3	**	3000/PCS

Absolute Maximum Ratings (T_C=25°C, unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D	4.2	A
Pulesd Drain Current	I_{DM}	30	A
Maximum Power Dissipation	P_D	1.4	W
Operating, Storage Temperature Range	T_J, T_{STG}	-55~150	°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	100	°C/W

Electrical Characteristics

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	30	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=24V, V_{GS}=0V$	-	-	1	μA
Gate -Source Leakage Current	I_{GSS}	$V_{GS}=\pm 12V, V_{DS}=0V$	-	-	±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1	-	1.8	V
Drain-Source On-stage Resistance	$R_{DS(ON)}$	$V_{GS}=10V, I_D=3.6A$	-	40	52	mΩ
		$V_{GS}=4.5V, I_D=2.8A$	-	58	74	
Body Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_{SD}=1A$	-	-	1	V

Dynamic Characteristics

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Input capacitance	C_{iss}	$V_{DS}=15V$ $V_{GS}=0V$ $f=1MHz$	-	-	375	pF
Output capacitance	C_{oss}		-	57	-	
Reverse transfer capacitance	C_{rss}		-	39	-	
Gate Resistance	R_g	$f=1MHz$	-	6	-	Ω
Total Gate Charge	Q_g	$V_{DS}=15V$ $V_{GS}=4.5V$ $I_D=5.8A$	-	4.34	-	nC
Gate Source Charge	Q_{gs}		-	0.6	-	
Gate Drain Charge	Q_{gd}		-	1.38	-	
Turn-on delay Time	$t_{d(on)}$	$V_{GS}=10V$ $V_{DS}=15V$ $R_L=2.7\Omega$ $R_G=3\Omega$	-	4.6	-	ns
Rise time	t_r		-	1.9	-	
Turn-off delay Time	$t_{d(off)}$		-	20.1	-	
Fall time	t_f		-	2.6	-	

Electrical Characteristics Diagrames

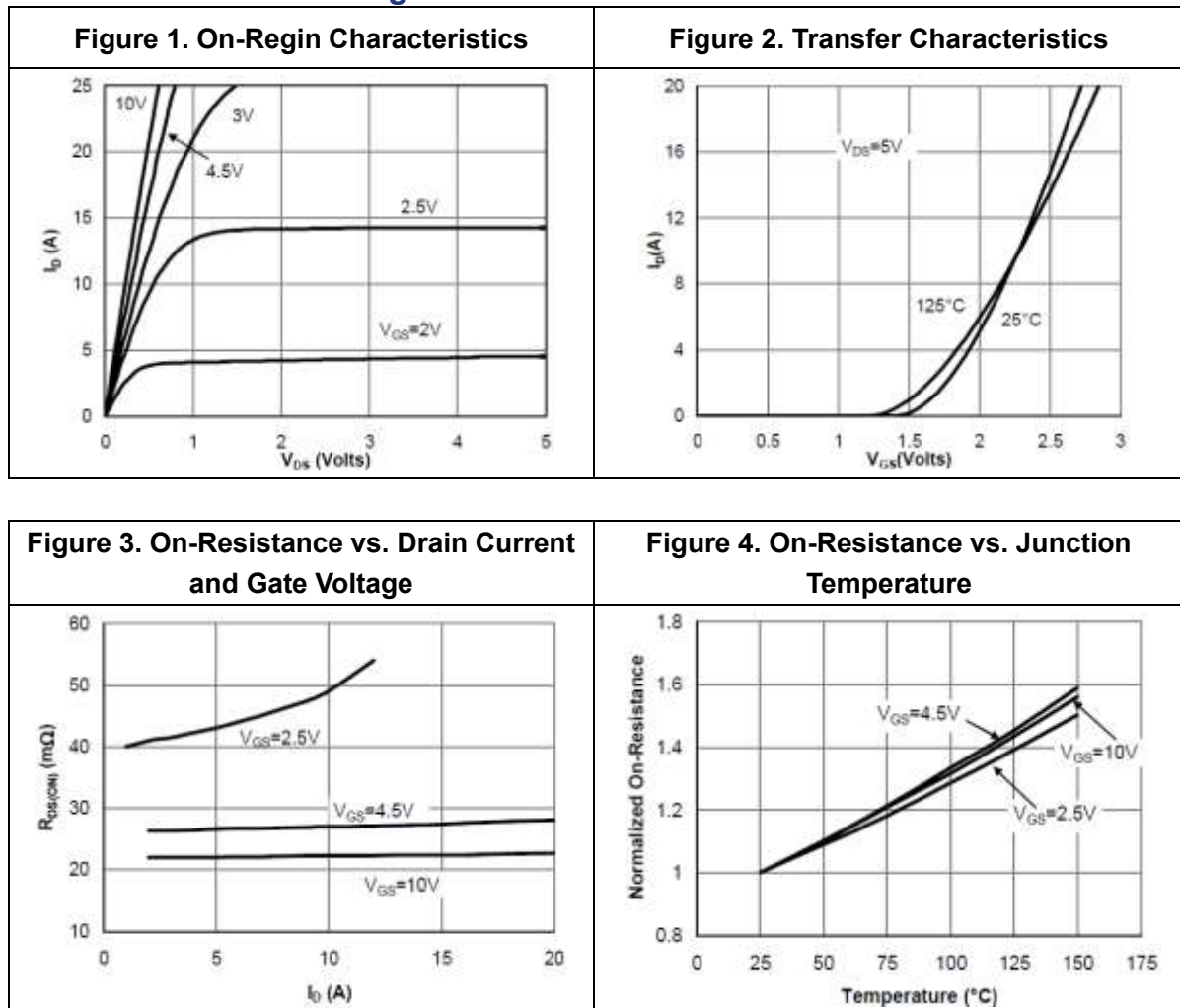


Figure 5. On-Resistance vs. Gate-Source Voltage

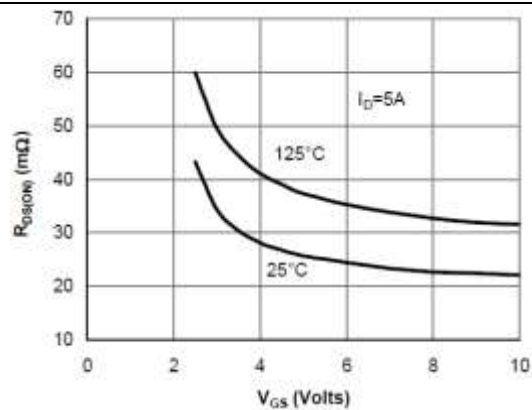
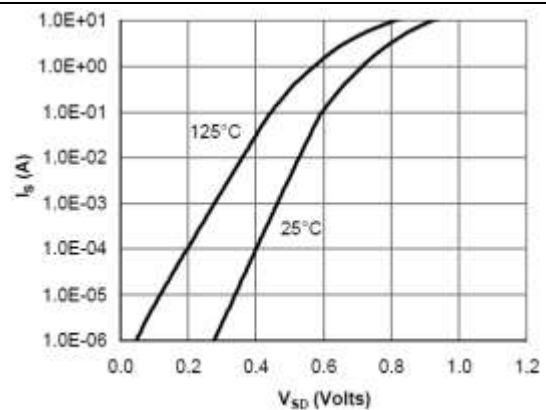
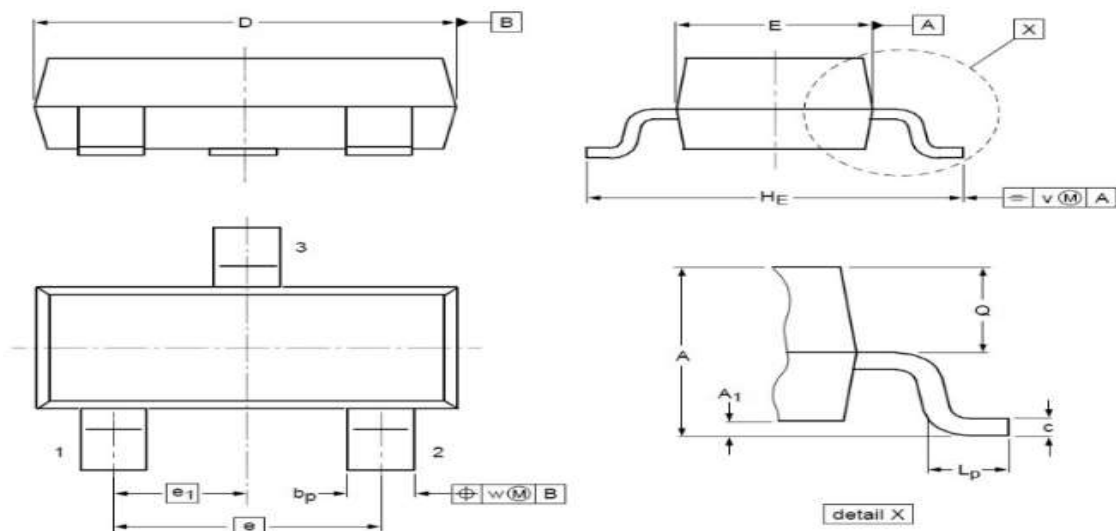


Figure 6. Body-Diode Characteristics



Physical Dimensions

SOT23-3



符号	尺寸(mm)			符号	尺寸(mm)		
	最小值	典型值	最大值		最小值	典型值	最大值
A	0.90	1.03	1.10	A1	0.01	0.05	0.10
bp	0.38	0.42	0.48	c	0.09	0.13	0.15
D	2.80	2.92	3.00	E	1.20	1.33	1.40
e	-	1.90	-	e1	-	0.95	-
HE	2.10	2.40	2.50	Lp	0.15	0.23	0.45
Q	0.45	0.49	0.55	v	-	0.20	-
w	-	0.10	-				